

Software Preparation for Commissioning

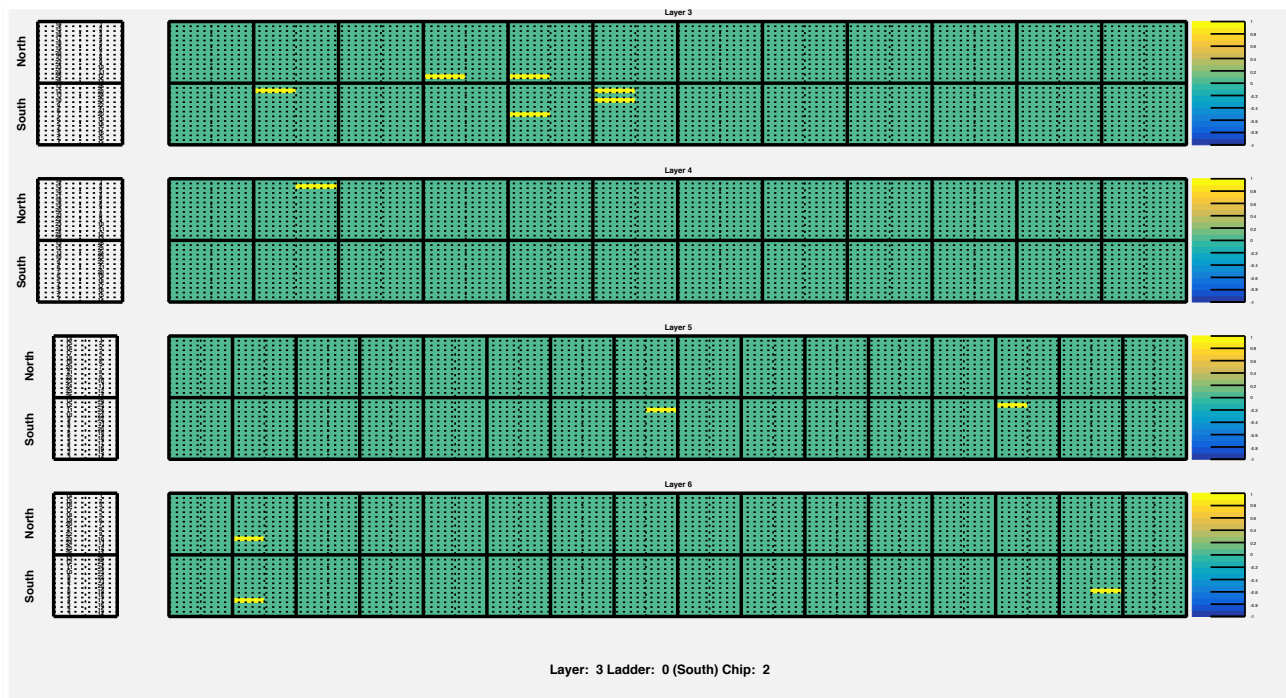
RIKEN/RBRC
Itaru Nakagawa

Commissioning without beam

1. Apply 100V bias (**HV GUI**). Diagnose any over current channels.
2. Power on a ladder by ladder (**LV GUIs**) and apply 100V bias. Run the calibration. Make sure the results appears in the expected ladder map in the **Calibration Display/Analyzer/Monitor**.
3. Diagnose missing channels and try to recover.
4. Random trigger noise run (**random external trigger**). Debug any large noise half ladder or channels (**online monitor**).
5. Tune the alert range of LV/HV voltage/current control panels (**alert features of LV/HV GUI**).
6. Save dead/hot channels in the database. (**Expert GUI**)



Noise rates

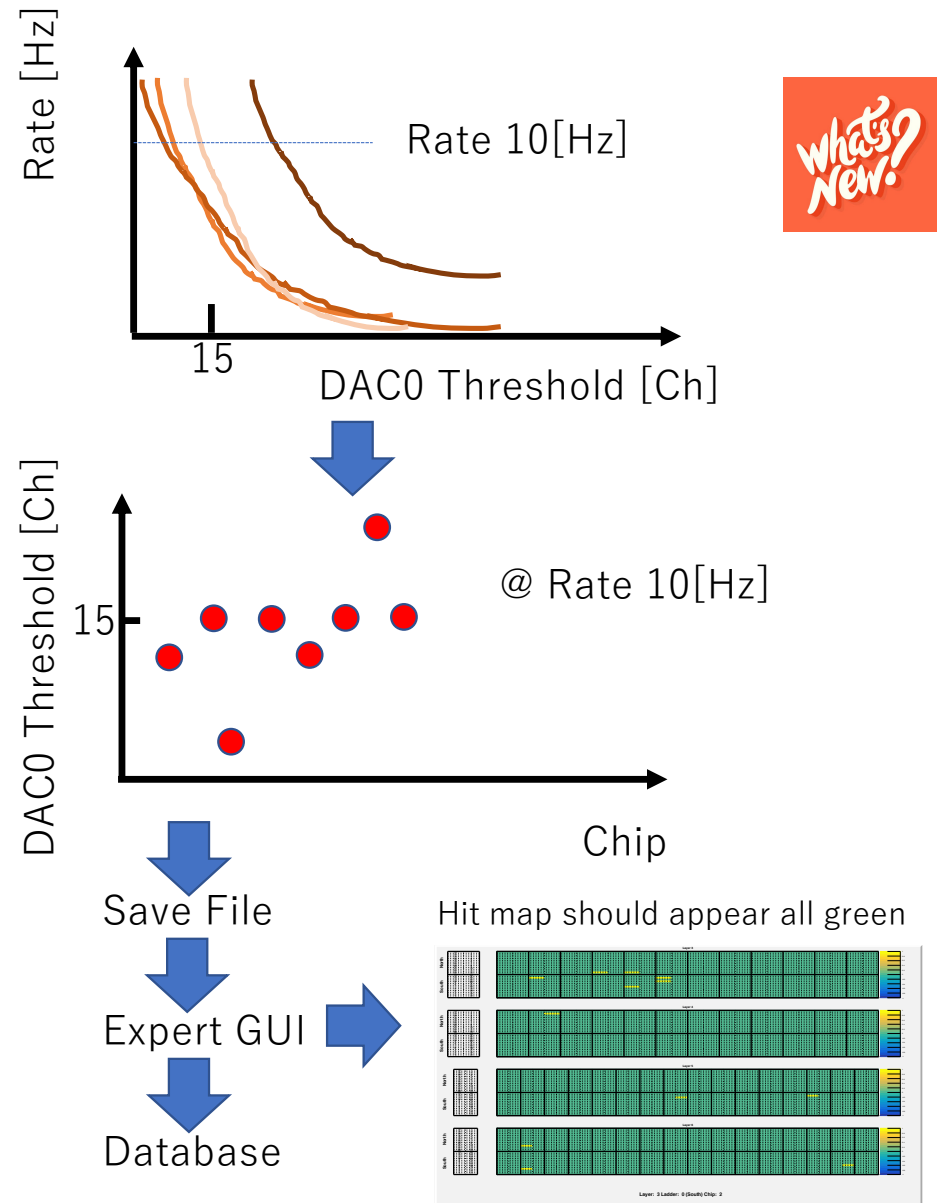


- Data should be taken with a [random external trigger](#).
- Noise rate are to be compared with the [online monitor](#) and check the uniformity of the noise.
- Spot noisy channels and too cold channels and diagnose.

DAC0 Scan

- Scan DAC0 value one-by-one [20, 19, 18, 17, ...] w/ random trigger.
- Optimize the DAC0 threshold for each Chip to give the same given rate. **Save threshold values (52 x 56) in file loadable to Expert GUI.**
- Customize DAC0 threshold setting chip-by-chip (**Expert-GUI**)
- This is the practice for the DAC0 threshold scan with the beam during commissioning. (S/N is also considered w/ beam)

*Additional feature to expert GUI

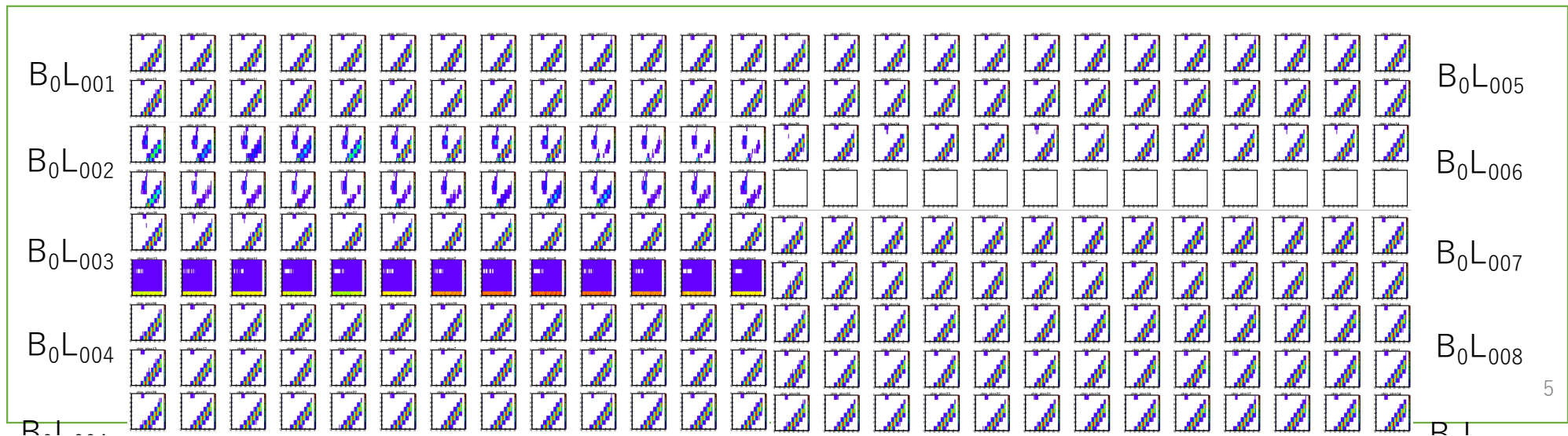


Calibration Display

Misaki Hata



- Should have a calibration results at a glance. At least the results of $\frac{1}{2}$ barrel appears in a single page. Is it possible?
- Perhaps a calibration mode can be implemented to the OnlineMonitor, but #of hits/strip is not sufficient. We definitely need ADC vs. Amplitude 2D plots.
- Any warning capability like the online monitor?

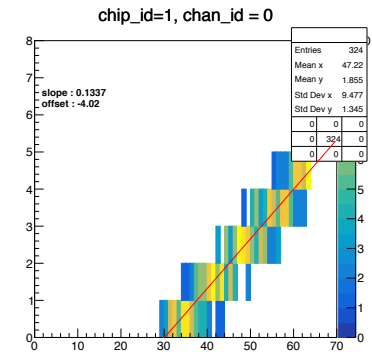


Calibration Result Analyzer

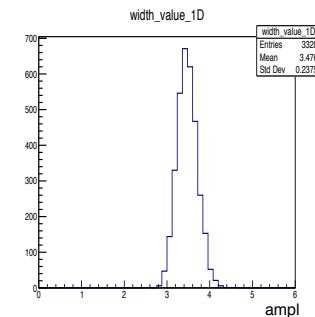
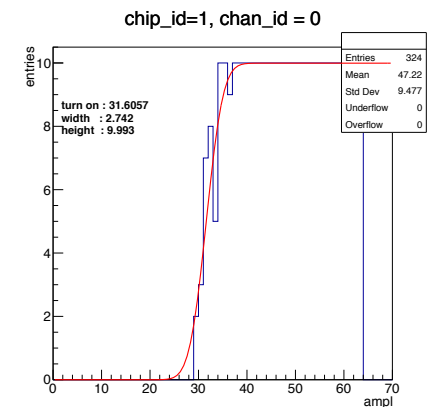
Calibration results are to be simplified into key characters and textualized such as :

- # of entries /chip (half entry, partial data drop to be detected)
- ADC vs. Amp slope
- Thresholds
- Noise levels
- # of bad channels/chip
- These textualized results are to be saved in the calibration database.

The codes developed for the ladder QA can be used. Are these codes in Fun4all?



Fit function : error function

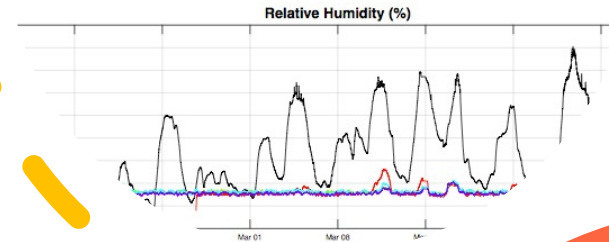
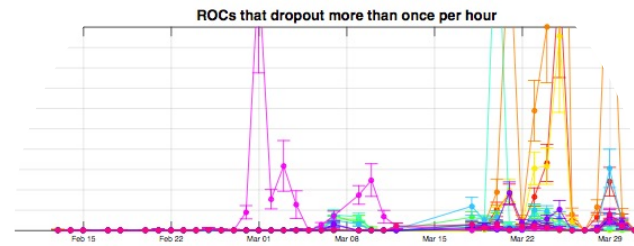


Cheng-Wei's slide
2021/8/11

Calibration Monitor

- Calibration run is to be executed regularly a couple of times a day.
- Results are to be monitored by the calibration monitor. The code is to be developed with the same framework with the stability monitor something like

```
%> StabilityMonitor.sh --calib
```



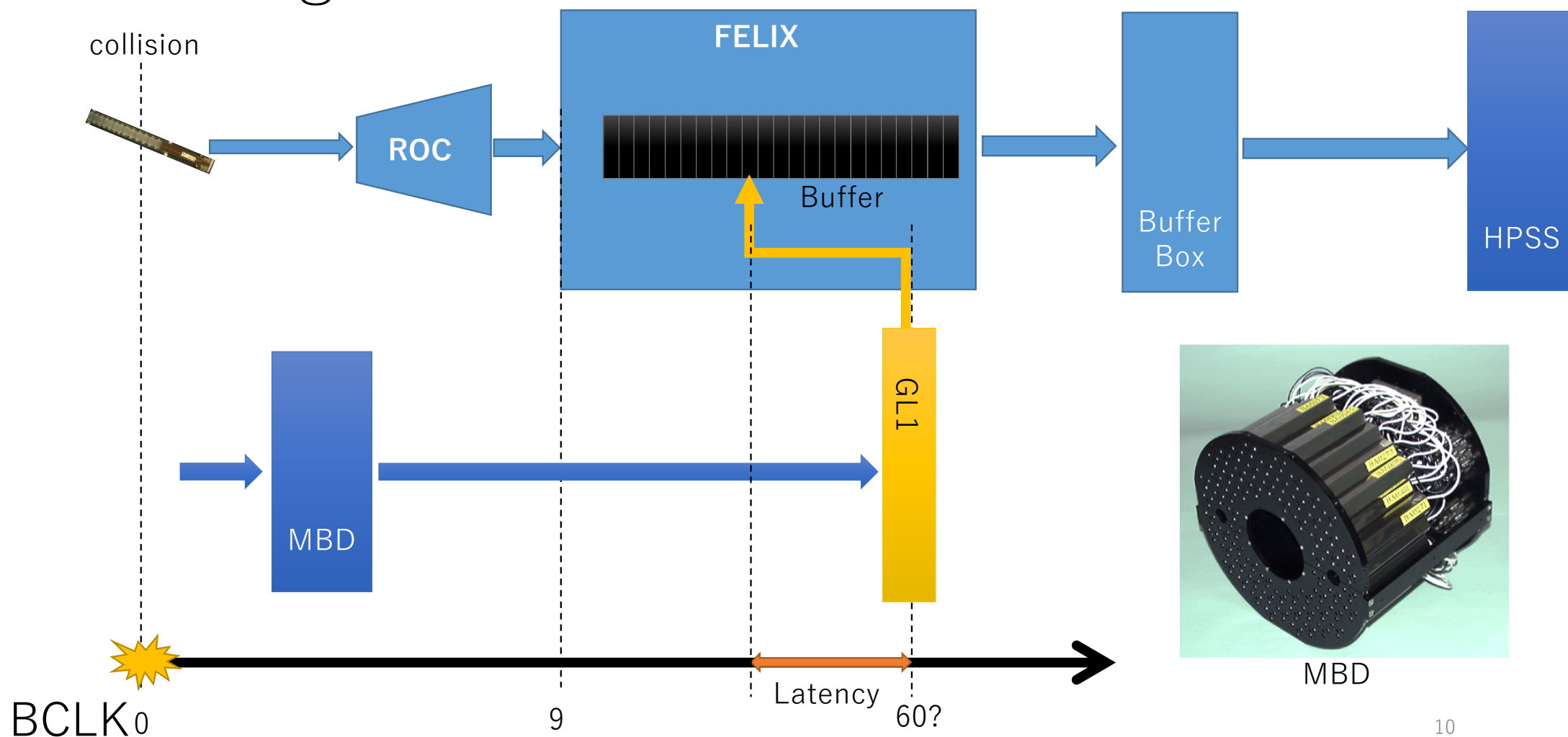
What's New?

Commissioning with beam

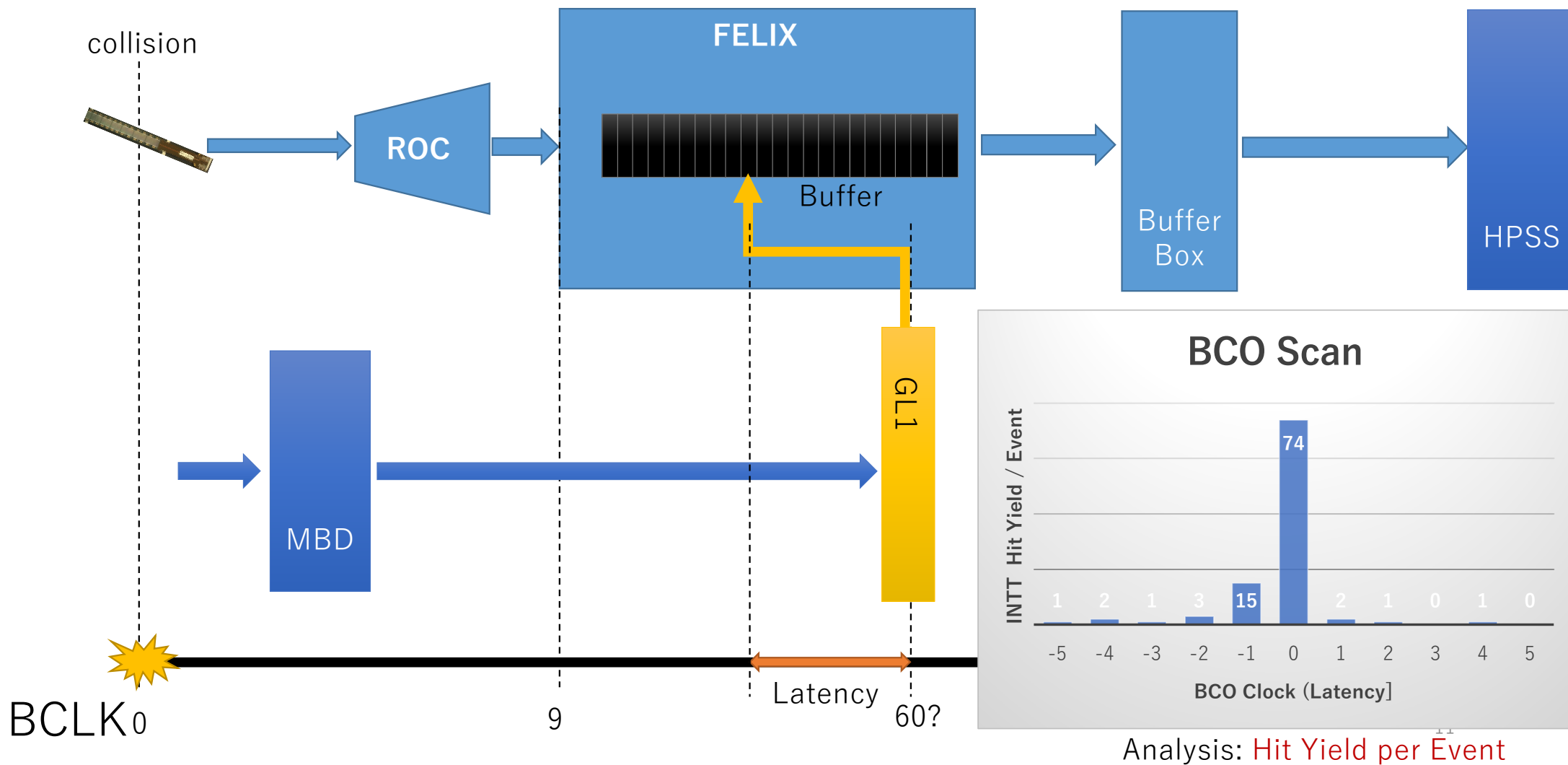
1. BCO Timing Scan (**INTT Hit Yield/Event**).
2. BCO Phase Scan fine tweak the timing with respect to BCO.
3. Mis-cabling check by the geometry (**Event Display**)
4. Diagnose missing channels and try to recover
5. Check yield uniformity (**Online Monitor, Stability Monitor**)
6. Gain matching between ladders or fine tweak noise
7. DAC Scan at HV=100V (**DAC Scan Analyzer**)
8. Bias Voltage Scan (**MIP/MPV Fitter**)
9. DAC0 threshold optimization. S/N evaluation chip by chip.

Timing Tune

Timing Tune



1. BCO Scan



2. BCO Phase Scan

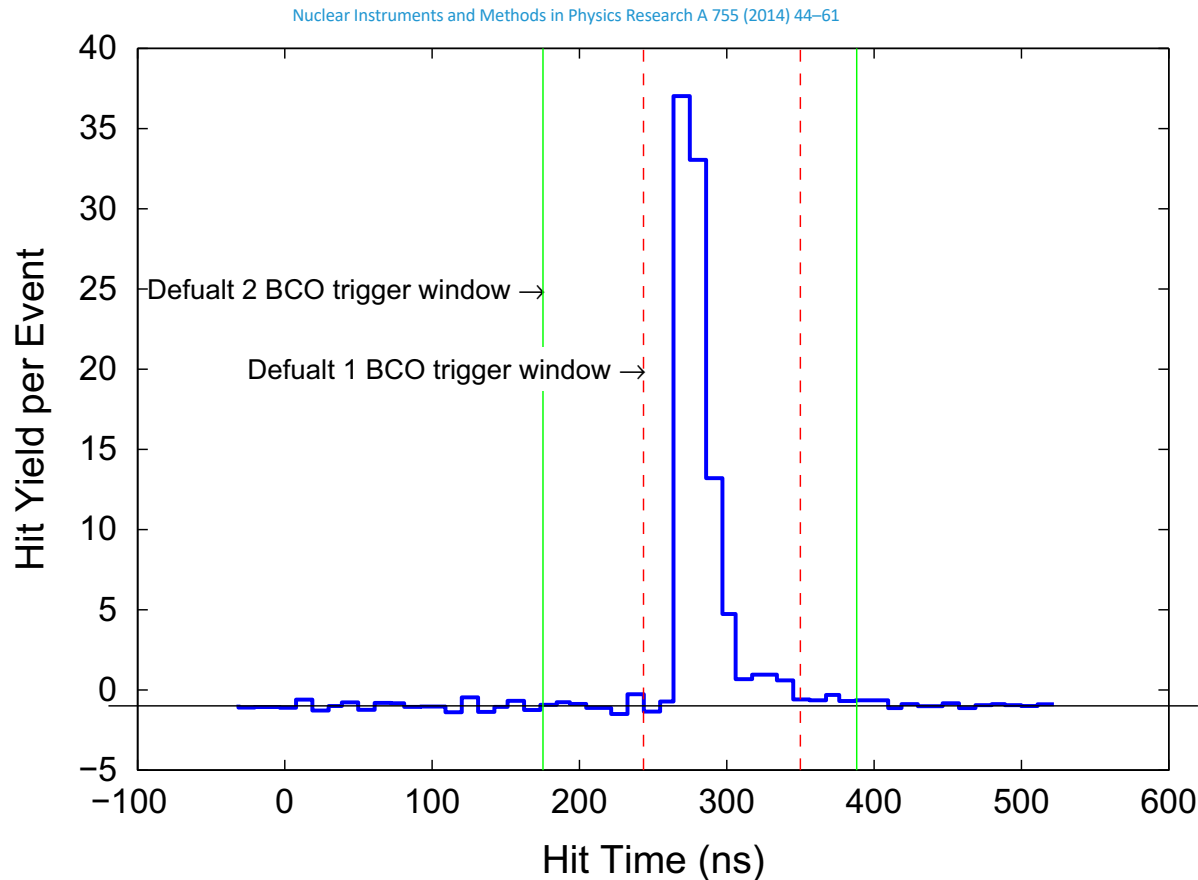


Fig. 32. Timing distribution of the FVTX hits relative to the RHIC beam clock.

6.1. Timing

The distribution in time of FVTX hits is studied relative to the RHIC collision time by comparing the hit rate at different FVTX delay values relative to the RHIC beam clock. The timing distribution for two sectors of wedges in the south arm is shown in Fig. 32. Most hits fall in a window ~ 30 ns wide.

Two standard trigger timing configurations were used during FVTX operation, as shown by the vertical lines in Fig. 32: during relatively low trigger rate running (in heavy ion systems) hits arriving in a time window two RHIC beam clocks (BCO) wide (1 BCO ~ 106 ns) are accepted. In high trigger rate p+p running, a 1 BCO-wide window is used to avoid recording accidental hits from neighboring beam crossings (1 BCO apart).

On 2023/01/12 22:22, Huang, Jin wrote:

That was exactly how it was done and highly recommended for intt too. It took few hours of a special low bunch fill to perform this scan, shifting BCO phase 19-20ns at a time. That appears the only way to set timing for the sub-bco delay
Jin

2. BCO Phase Scan

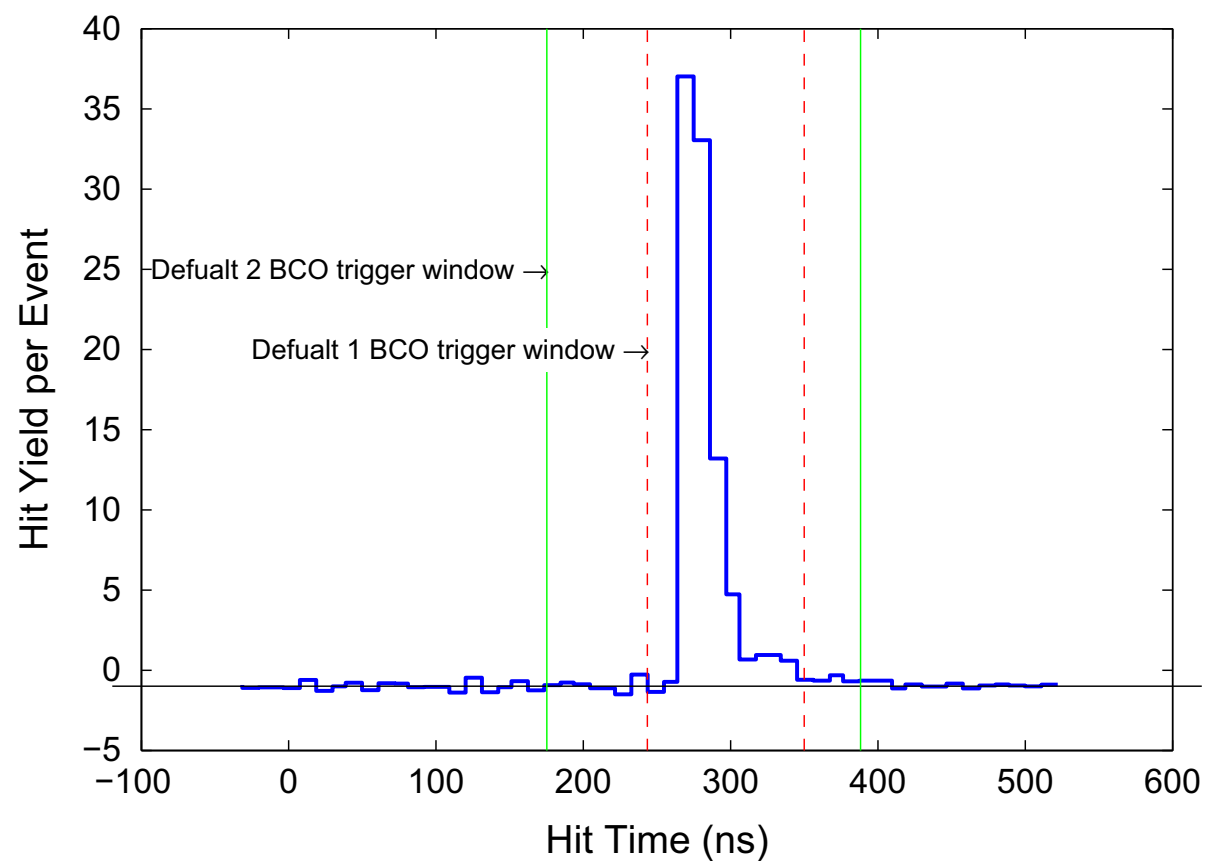
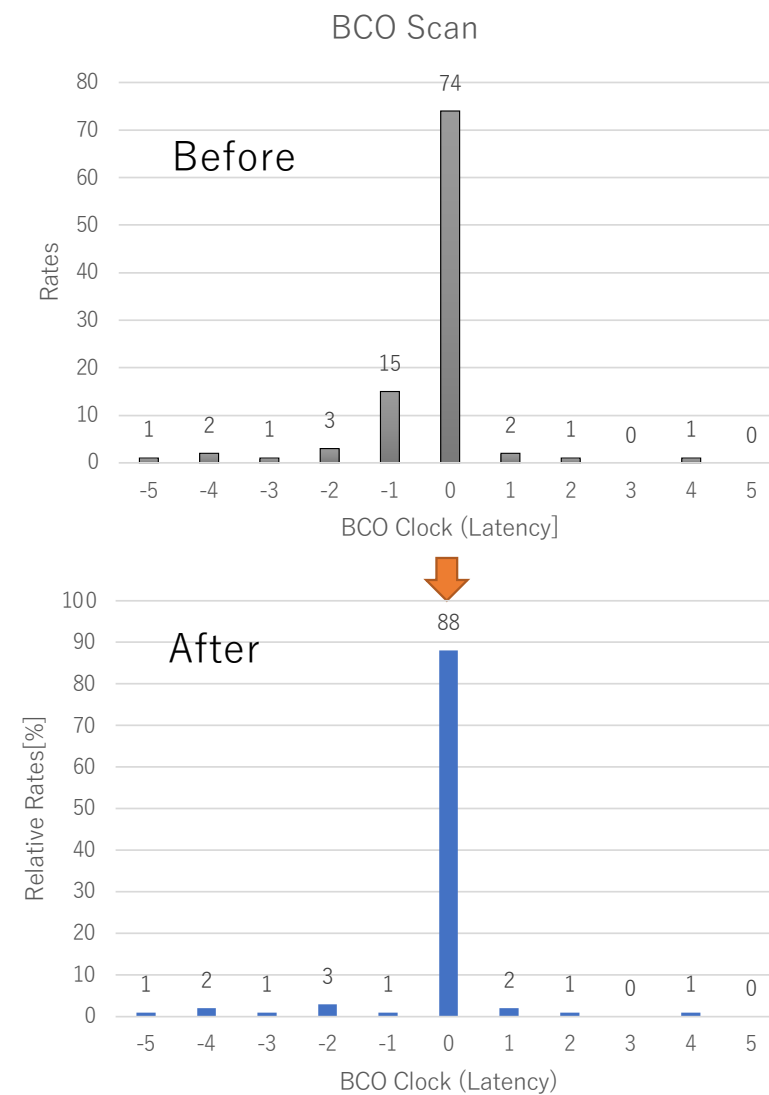
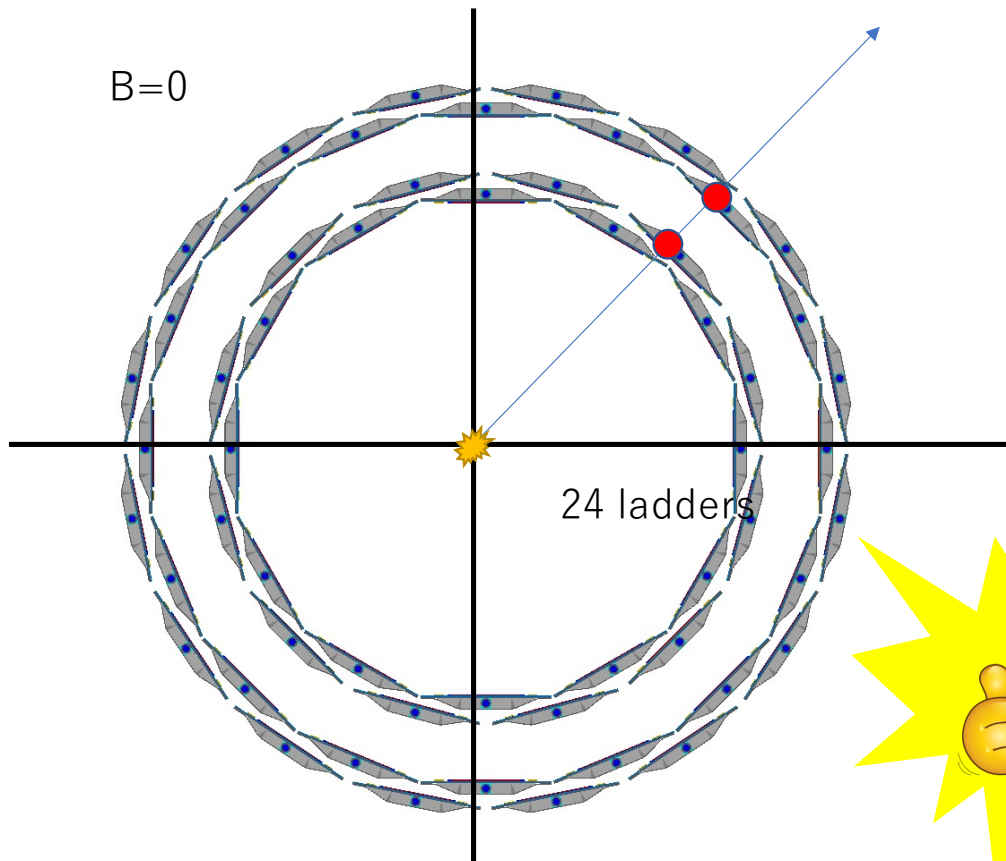


Fig. 32. Timing distribution of the FVTX hits relative to the RHIC beam clock.

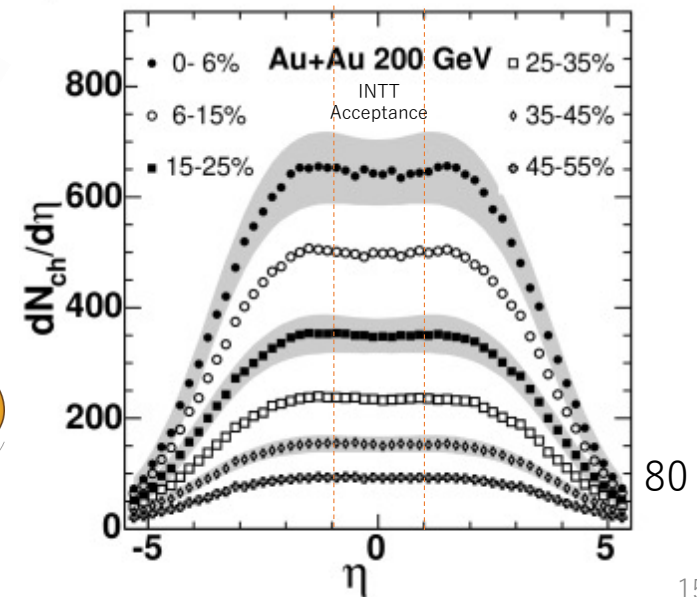
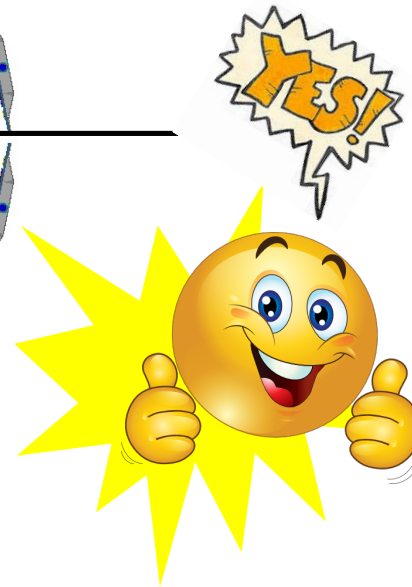


Ladder Geometrical Check

3. Hit Matching

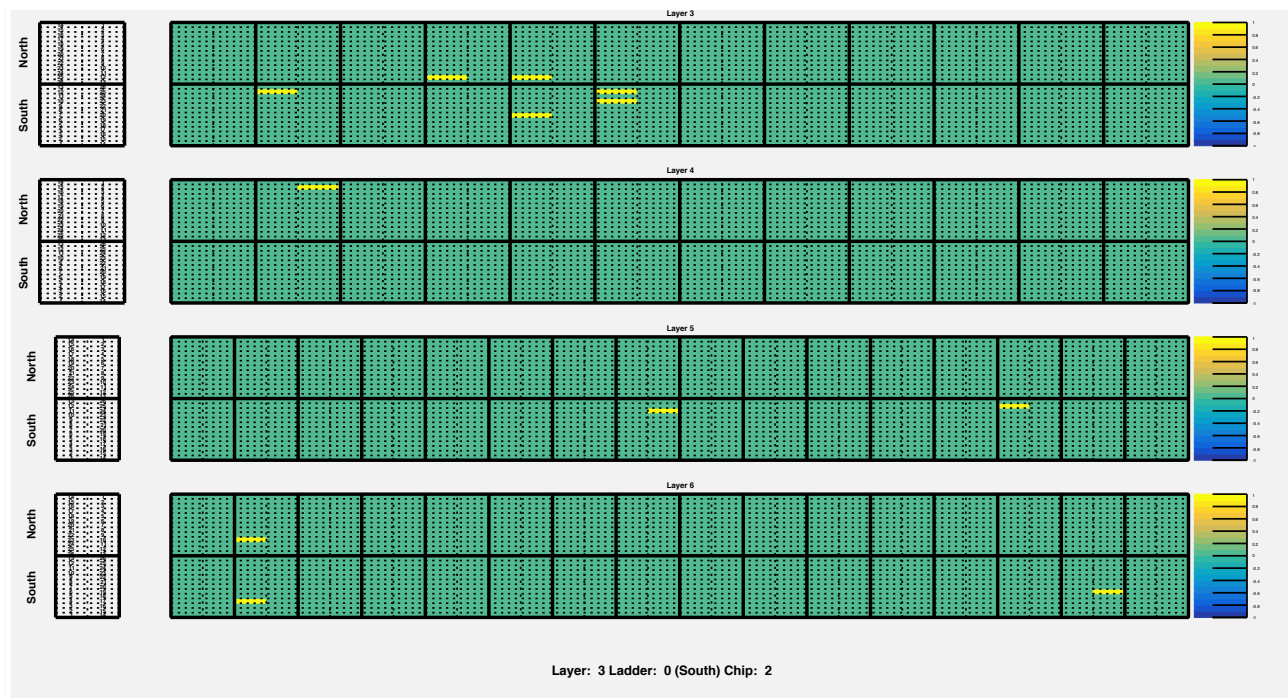


- In early stage of the commissioning, sPHENIX is operated with magnetic field off.
 - Tracks are expected to be straight.
 - At the 45-55% centrality collision, $80/|\eta|$ tracks \rightarrow 4 tracks/half ladder \rightarrow 0.15 hit/chip.
 - Matching hits between L0 and L1 can be identified by eye using the **event display** without fancy tracking algorithm.



Hit Rate Uniformity Check

Hit Rate Uniformity Check



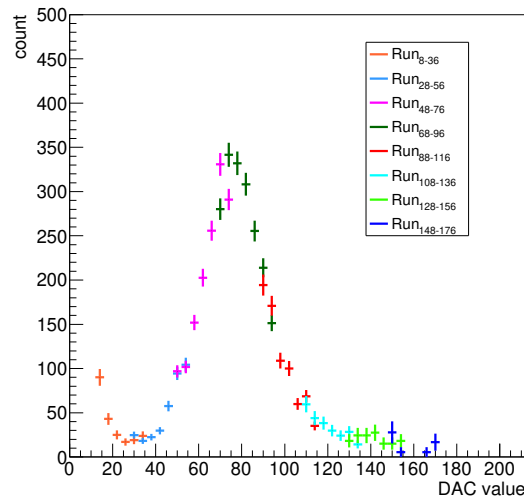
- Definitely need the **online monitor** working.
- Some non—uniformity can be observed by:
 - Bad cable contact
 - Dead channel
 - Hot channel
 - Gain variation
 - ...
- Dead/Hot channel detector is to be implemented.
- This check suppose to be executed periodically after the DAC0 threshold optimization

DAC Scan

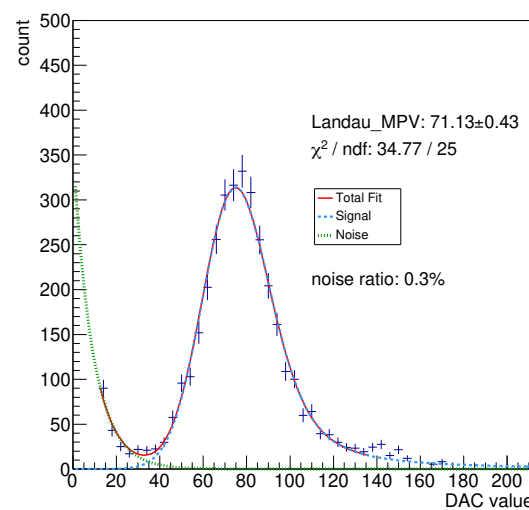
DAC Scan

Scan	1	2	3	4	5	6	7	8
DAC0	8	28	48	68	88	108	128	148
1	12	32	52	72	92	112	132	152
2	16	36	56	76	96	116	136	156
3	20	40	60	80	100	120	140	160
4	24	44	64	84	104	124	144	164
5	28	48	68	88	108	128	148	168
6	32	52	72	92	112	132	152	172
7	36	56	76	96	116	136	156	176

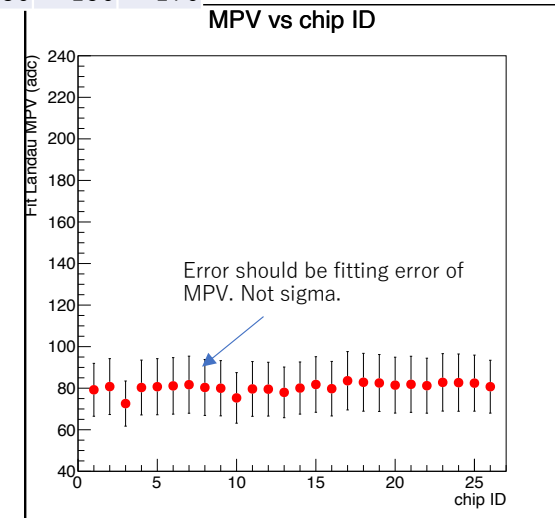
ビームテストと同じ設定で良いか？
オーバーラップ
binは二つ？



- Chip-by-Chip Base
- Clustering (**Optimize offset value**)
- Normalization btwn adjacent runs
- Concatenate all runs



- Fitting with Landau+Gaussian convolution function.



Half ladder by half ladder



All ladders

Save all fitting parameters:
MPV, Width, ...

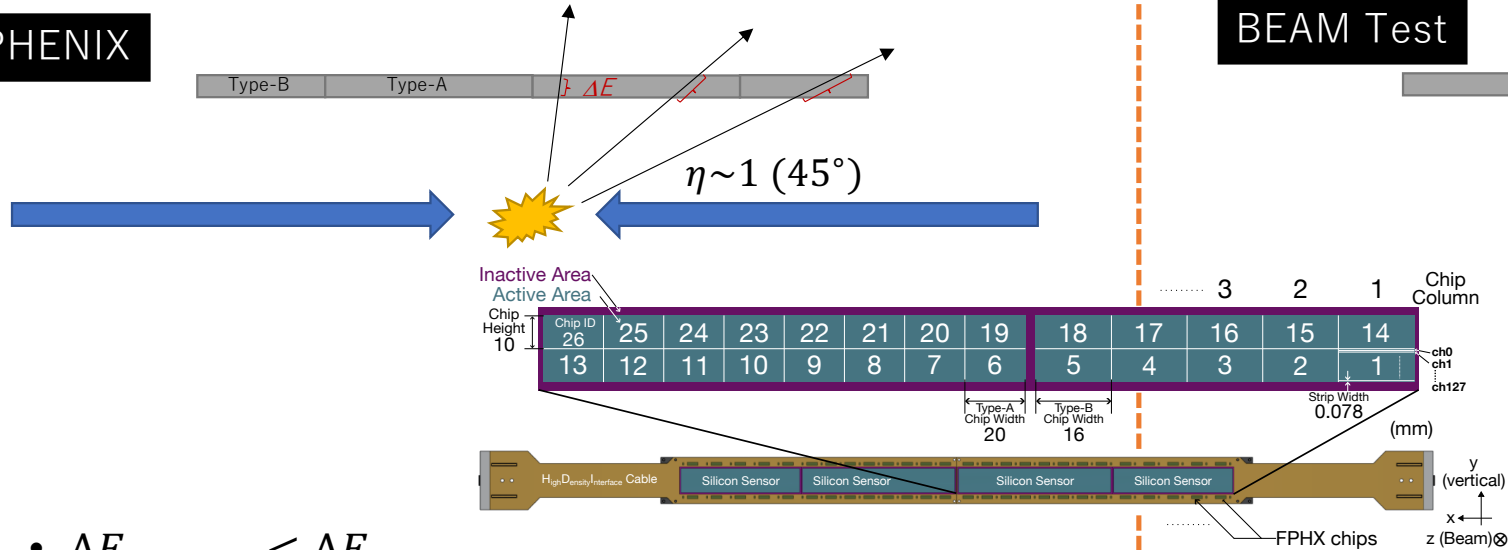
How Energy Deposit Looks like in sPHENIX?

DACのオーバーフローが出ちゃうか？

sPHENIX

BEAM Test

Cheng-Wei's slide 2022/4/15

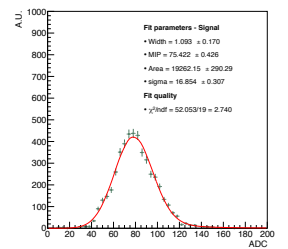


- $\Delta E_{Type-A} < \Delta E_{Type-B}$
- $\Delta E_{Chip13} < \Delta E_{Chip12} < \dots < \Delta E_{Chip1}$
- $\Delta E_{Chip1} \sim \Delta E_{Chip13} \times \sqrt{2}$ ($\eta \sim 1$)
- $\Delta E_{Chip13} = \Delta E_{Chip26}$

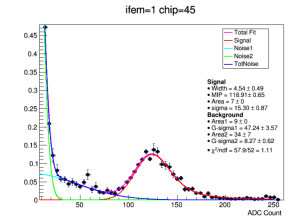
- $\Delta E_{Type-A} = \Delta E_{Type-B}$
- $\Delta E_{Chip13} = \Delta E_{Chip12} = \dots = \Delta E_{Chip1}$
- $\Delta E_{Chip13} = \Delta E_{Chip26}$

$\Delta E_{Chip13}^{sPHENIX} @50V \sim \Delta E_{Chip13}^{ELPH2021} @50V, \Delta E_{Chip13}^{sPHENIX} @100V \sim \Delta E_{Chip13}^{FNAL2019} @100V ?$
To be studied by a **simulation** in advance.

Testbeam2021, 50 V
Positron beam, 1 GeV
DAC Scan all 11



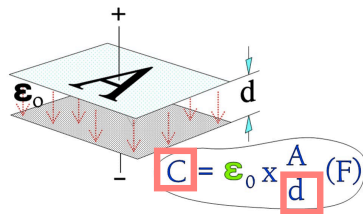
Testbeam2019, 100 V
Proton beam, 120 GeV



Bias Voltage Scan

Bias Voltage Dependence

Cheng-Wei's slide 2022/4/15



Based on the theory :

$$C \propto \frac{1}{d} \propto \frac{1}{\sqrt{V}} \propto \frac{1}{\text{signal}}$$

$$W_d = \sqrt{2\epsilon(V + V_{bi})/Ne} = \sqrt{2\rho\mu\epsilon(V + V_{bi})}$$

$$C = \sqrt{\frac{\epsilon_0 \epsilon_r}{2\mu\rho|V|}} \cdot A$$

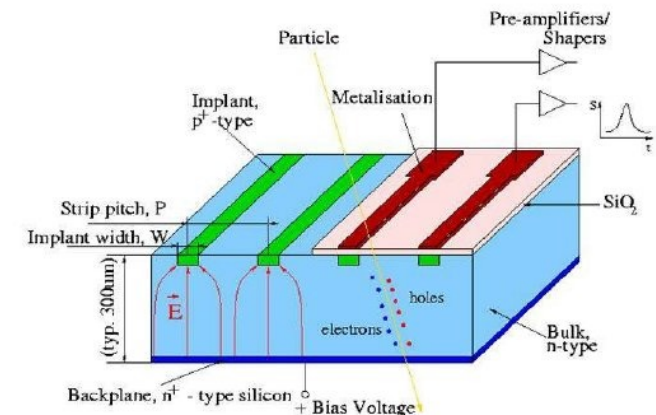
$$\frac{dE/dx \cdot d}{I_0} = \frac{3.87 \cdot 10^6 \text{ eV/cm} \cdot 0.03 \text{ cm}}{3.62 \text{ eV}} \approx 3.2 \cdot 10^4 \text{ e}^- \text{h}^+ \text{-pairs}$$

Signal

C : capacitance
d : the distance of the depletion region
V : supply bias voltage
signal : edep

Itaru's Slide 2022/06/22

Principles of operation



LL

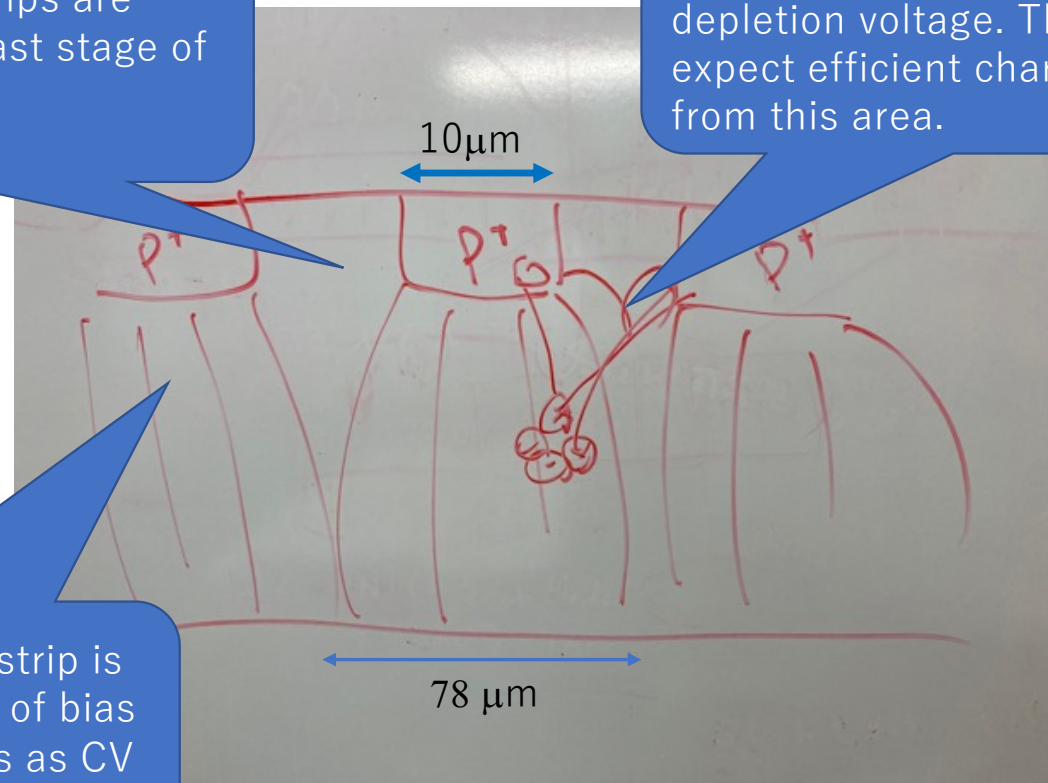
Electric field at non-fully depleted voltage

Electric field between strips are developed towards the last stage of fully depletion voltage.

This area between strips might not be depleted even slightly below the depletion voltage. Thus we cannot expect efficient charge collection from this area.

REALITY

The electric field just below strip is well developed as a function of bias voltage. This directly appears as CV response.

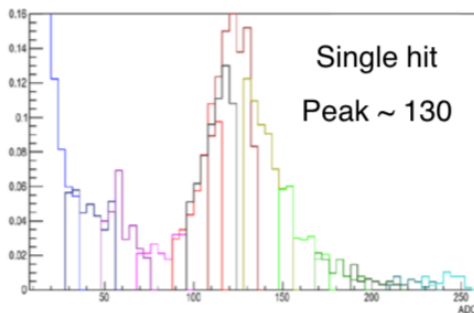


The best way to prove this hypothesis is to see the position dependence of the resolution within the strip width. We'll see a dip in the efficiency distribution around the edge of a strip.

Not sure if this is doable with cosmic ray...

Bias Voltage Scan Plan

- Importance: It is likely we end up with operating $<100V$ due to over current of some silicons.
- We need to know the collecting # of electrons below 100V.

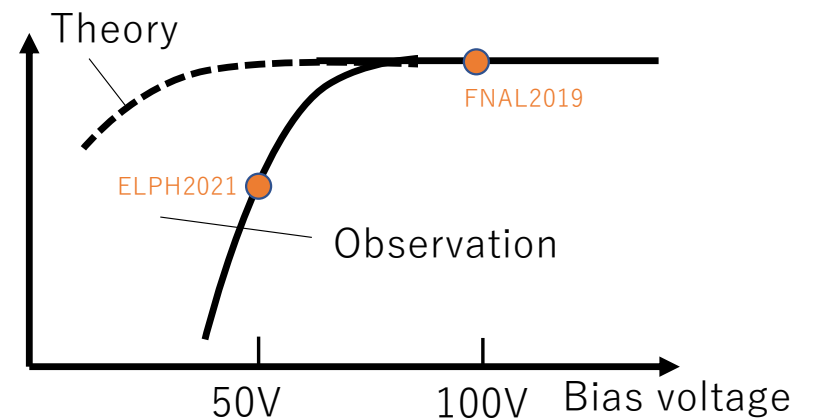


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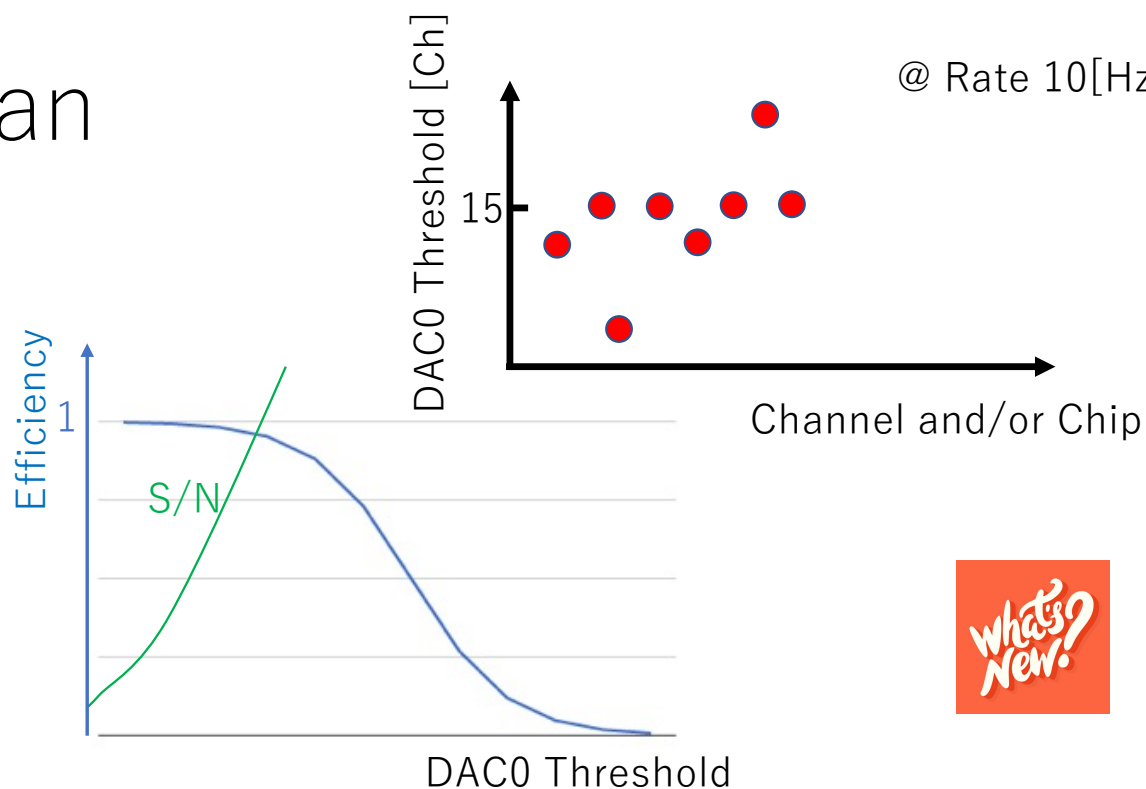
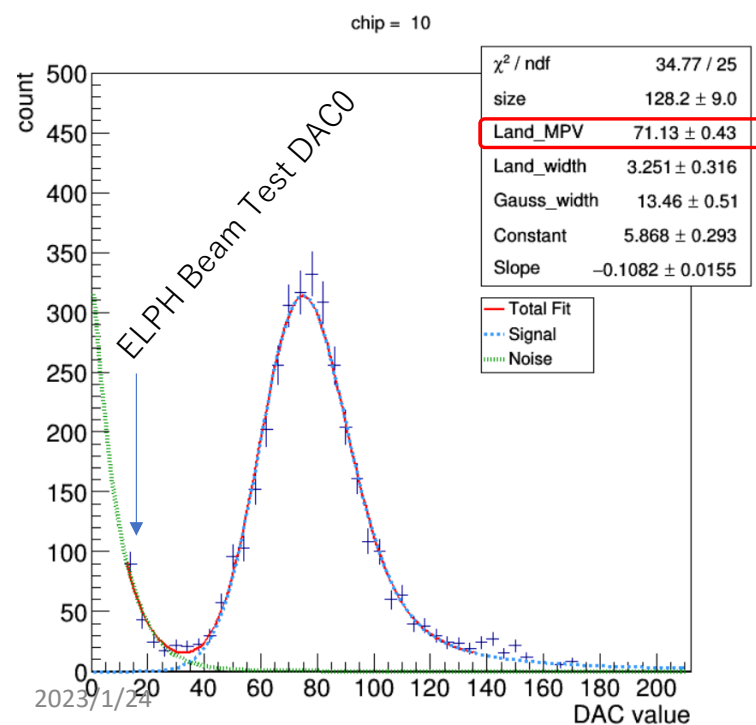
- Scan at 90V, 80V, 70V, 60V, 50V only around MIP region.
- Need immediate semi-online analysis (**DAC Scan code**) if data is satisfactory to cover MPV peak.
- The goal is to make the plot of **MPV vs. Bias voltage**.
- Not sure if we can run a simulation.

MPV vs Bias Voltage



DAC0 Threshold Scan

DAC0 Threshold Scan



DAC0	12	13	14	15	16	17	18
S/N							
Efficiency							

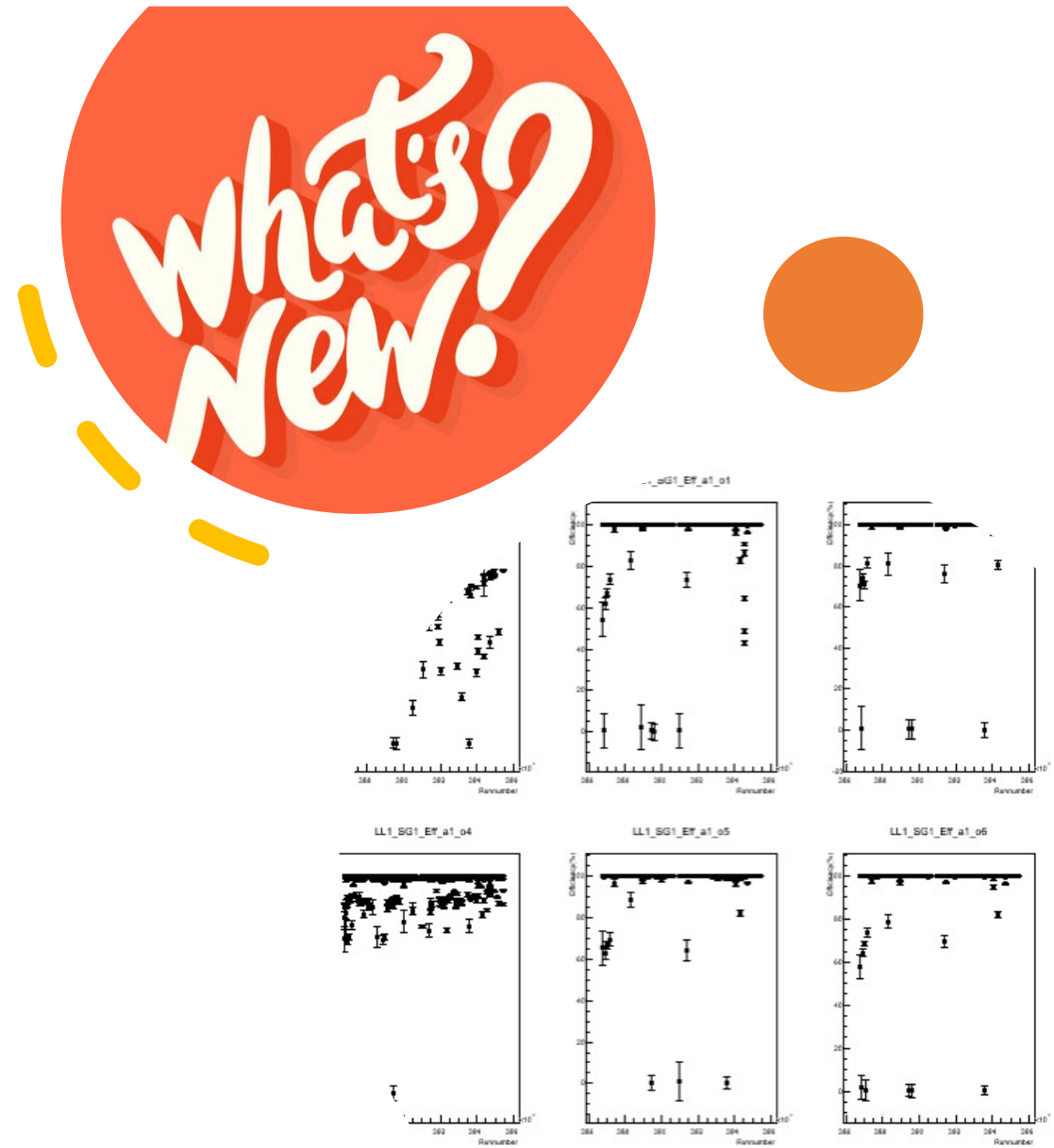
- The final DAC0 threshold is to be determined by the S/N. The philosophy is to keep the signal fraction as high as possible within the tolerable noise rate.

Monitoring (Advices from previous discussion)

1. Define online monitor. Develop and test anomaly (dead/hot channel) checker.
2. Establish flushing anomaly checker results to database.

Stability Monitor

- Normalized hit rates/Chip, ADC peak position, S/N, etc. are again, textualized (part of online monitor?) and be saved in the calibration database.
- Then we should develop the stability monitor by plotting above key performance parameters as a function of time.

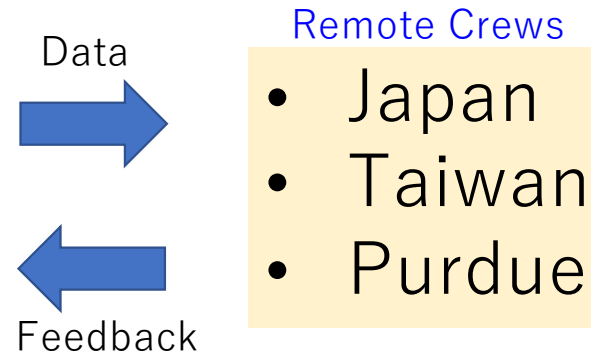


Manpower operation during commissioning

Onsite Crews

- Rachid
- Genki
- Maya
- Itaru : Feb. 20th –
- Cheng-Wei : March 2nd -
- Joseph : Middle of Feb –
- Jaein : March 1st -
- Else?

Hardware debugging, data taking,
change setting, logging incidents,...



Analysis



- Once we have a beam, the data taking is 24 hours.
- As long as we have a plan, we'll continue data taking with the INTT standalone DAQ independently from other subsystem data taking.
- The hall access will be coordinated with other subsystems.
- We will be blind immediately without the analysis code and cannot move forward!

Summary

- Various analyses and display codes are required for each measurement in commissioning. **Need to prepare all necessary codes in advance!!**
- Depending on the results, the INTT operating parameters are determined and the next measurement is made, so results are required immediately. Compared to single ladder analysis, the number of channels and the amount of data are overwhelmingly large.
- Data analysis is not an amount that can be handled on-site. Need feedback from remote analysis crews.
- Since we cannot have every INTT team members to be on-site, the commissioning program is designed to analyze the data remotely and provide feedback to the on-site.
- Volunteers are always welcome!

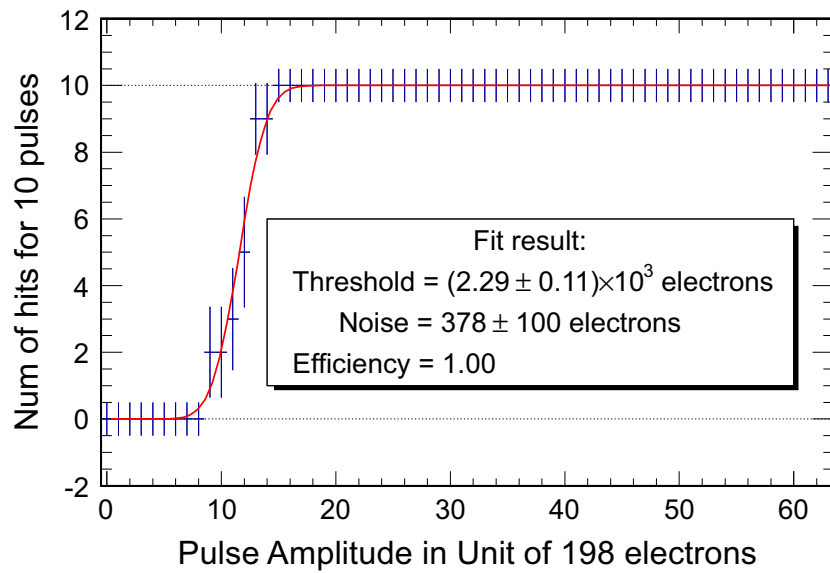


Fig. 35. Typical calibration data for a single channel (data points), fit with a normal cumulative distribution function.

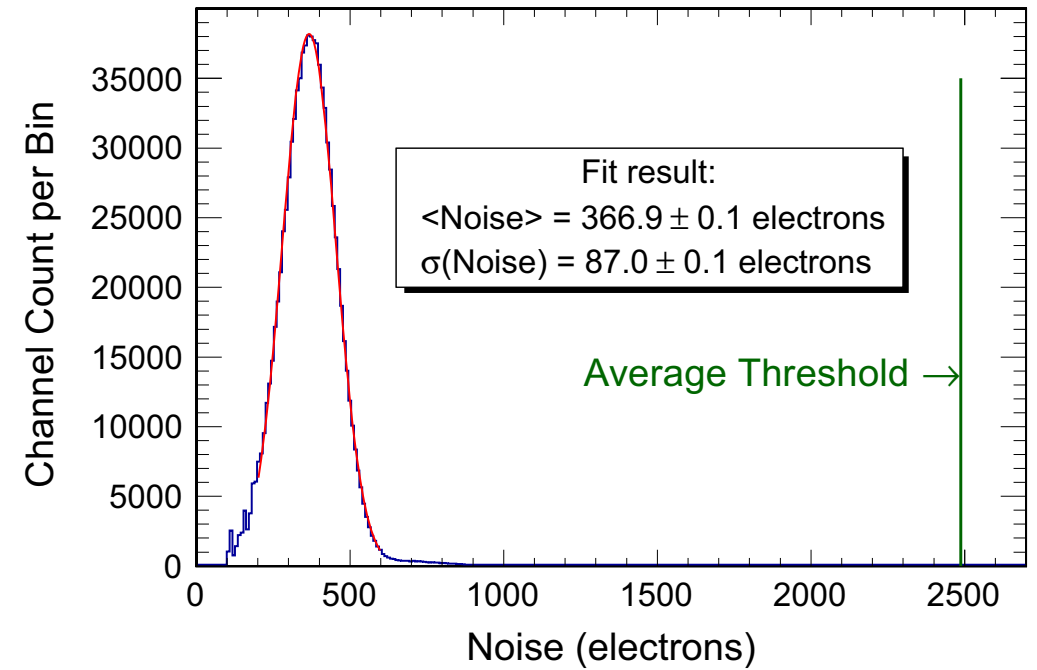


Fig. 36. Histogram of the noise parameter, σ , for all channels under operating conditions, in a typical calibration run. A Gaussian distribution fit to the data gives a mean noise level of 367 electrons. The nominal discriminator threshold at ~ 2500 electrons is shown by the vertical line.